

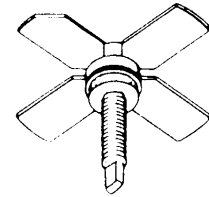
# MS1261

## RF & MICROWAVE TRANSISTORS VHF MOBILE APPLICATIONS

- Features
- 175 MHz
- 12.5 VOLTS
- P<sub>OUT</sub> = 15 WATTS
- G<sub>p</sub> = 12 dB MINIMUM
- INPUT IMPEDANCE MATCHING
- COMMON EMITTER CONFIGURATION

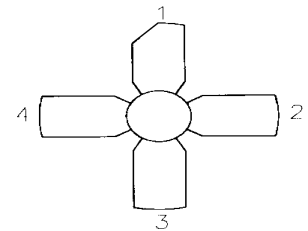
### DESCRIPTION:

The MS1261 is a Class C 12.5V epitaxial silicon NPN planar transistor designed primarily for UHF communications. This device utilizes a gold metallized, emitter ballasted die geometry for superior reliability and infinite VSWR capability.



**.280 4L STUD (M122)**  
epoxy sealed

### PIN CONNECTION



1. Collector      3. Base  
2. Emitter        4. Emitter

### ABSOLUTE MAXIMUM RATINGS (T<sub>case</sub> = 25°C)

| Symbol            | Parameter                 | Value       | Unit |
|-------------------|---------------------------|-------------|------|
| V <sub>CBO</sub>  | Collector-Base Voltage    | 36          | V    |
| V <sub>CEO</sub>  | Collector-Emitter Voltage | 18          | V    |
| V <sub>CES</sub>  | Collector-Emitter Voltage | 36          | V    |
| V <sub>EBO</sub>  | Emitter-Base Voltage      | 4.0         | V    |
| I <sub>C</sub>    | Device Current            | 2.5         | A    |
| P <sub>DISS</sub> | Power Dissipation         | 34          | W    |
| T <sub>J</sub>    | Junction Temperature      | +200        | °C   |
| T <sub>STG</sub>  | Storage Temperature       | -65 to +150 | °C   |

### Thermal Data

|                      |                                  |      |      |
|----------------------|----------------------------------|------|------|
| R <sub>TH(J-C)</sub> | Thermal Resistance Junction-case | 8.75 | °C/W |
|----------------------|----------------------------------|------|------|

**ELECTRICAL SPECIFICATIONS (T<sub>case</sub> = 25°C)**
**STATIC**

| Symbol                  | Test Conditions  | Value      |      |            | Unit      |
|-------------------------|--|------------|------|------------|-----------|
|                         |  | Min.       | Typ. | Max.       |           |
| <b>BV<sub>CES</sub></b> | <b>I<sub>C</sub> = 50 mA</b> <b>V<sub>BE</sub> = 0V</b>  | <b>36</b>  | ---  | ---        | <b>V</b>  |
| <b>BV<sub>CEO</sub></b> | <b>I<sub>C</sub> = 15 mA</b>                             | <b>18</b>  | ---  | ---        | <b>V</b>  |
| <b>BV<sub>EBO</sub></b> | <b>I<sub>E</sub> = 2.5 mA</b> <b>I<sub>C</sub> = 0mA</b> | <b>4.0</b> | ---  | ---        | <b>V</b>  |
| <b>I<sub>CBO</sub></b>  | <b>V<sub>CE</sub> = 15 V</b> <b>I<sub>E</sub> = 0mA</b>  | ---        | ---  | <b>1</b>   | <b>mA</b> |
| <b>H<sub>FE</sub></b>   | <b>V<sub>CE</sub> = 5 V</b> <b>I<sub>C</sub> = 250mA</b> | <b>20</b>  | ---  | <b>200</b> | ---       |

**DYNAMIC**

| Symbol                 | Test Conditions   | Value     |      |           | Unit      |
|------------------------|---|-----------|------|-----------|-----------|
|                        |   | Min.      | Typ. | Max.      |           |
| <b>P<sub>OUT</sub></b> | <b>f = 175 MHz</b> <b>P<sub>IN</sub> = 1W</b> <b>V<sub>CE</sub> = 12.5V</b> | <b>15</b> | ---  | ---       | <b>W</b>  |
| <b>η<sub>c</sub></b>   | <b>f = 175 MHz</b> <b>P<sub>IN</sub> = 1W</b> <b>V<sub>CE</sub> = 12.5V</b> | <b>60</b> | ---  | ---       | <b>%</b>  |
| <b>G<sub>p</sub></b>   | <b>f = 175 MHz</b> <b>P<sub>IN</sub> = 1W</b> <b>V<sub>CE</sub> = 12.5V</b> | <b>12</b> | ---  | ---       | <b>dB</b> |
| <b>C<sub>OB</sub></b>  | <b>f = 1 MHz</b> <b>V<sub>CB</sub> = 12.5V</b>                              | ---       | ---  | <b>45</b> | <b>pf</b> |

**IMPEDANCE DATA**

| FREQ    | Z <sub>IN</sub> (Ω) | Z <sub>CL</sub> (Ω) |
|---------|---------------------|---------------------|
| 175 MHz | 1.2 – j0.4          | 5.2 + j1.1          |

**P<sub>OUT</sub> = 15W**  
**V<sub>CC</sub> = 12.5V**

**PACKAGE MECHANICAL DATA**

